Panasonic Electronic Components - MN101CF77GXN Datasheet

Welcome to E-XFL.COM

What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	MN101C
Core Size	8-Bit
Speed	20MHz
Connectivity	I²C, UART/USART
Peripherals	DMA, PWM, WDT
Number of I/O	53
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	6K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 7x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	-
Purchase URL	https://www.e-xfl.com/product-detail/panasonic/mn101cf77gxn

❑ MN101C77 Series

Type	MN101C77A	MN101C77C	MN101C77D	MN101C77F	MN101CF77G
Internal ROM type	Mask ROM				FLASH
ROM (byte)	32K	48K	64K	96K	128K
RAM (byte)	1.5K	3K	6K		
Package (Lead-free)	LQFP064-P-1414	LQFP064-P-1414, TQFP064-P-1010C	LQFP064-P-1414		LQFP064-P-1414, TQFP064-P-1010C
Minimum Instruction Execution Time	[Standard] 0.1 µs (at 2.5 V to 3.6 V, 20 MHz)* 0.2 µs (at 2.1 V to 3.6 V, 10 MHz)* 0.5 µs (at 1.8 V to 3.6 V, 4 MHz)* 62.5 µs (at 1.8 V to 3.6 V, 32 kHz)* [Double speed] 0.119 µs (at 2.5 V to 3.6 V, 8.39 MHz)* *: The operation guarantee range for flash memory built-in type is 2.7 V to 3.6 V.				

■ Interrupts

RESET. Watchdog. External 0 to 4. Timer 0. Timer 1. Timer 4 to 6. Timer 7 (2 systems). Time base. Serial 0 reception. Serial 0 transmission. Serial 1 reception. Serial 1 transmission. Serial 3. Serial 4. Automatic transfer finish. A/D conversion finish. Key interrupts (8 lines)

■ Timer Counter

8-bit timer × 5

Timer 0 .....Square-wave/8-bit PWM output. Event count. Remote control carrier output. Pulse width measurement

Timer 1 .....Square-wave output. Event count. Synchronous output event

Timer 4 .....Square-wave/8-bit PWM output. Event count. Pulse width measurement. Serial 1 baud rate timer

Timer 5 .....Square-wave/8-bit PWM output. Event count. Pulse width measurement. Serial 0 baud rate timer

Timer 6 .....8-bit freerun timer

Timer 0, 1 can be cascade-connected

16-bit timer × 1

Timer 7 .....Square-wave/16-bit PWM output (cycle/duty continuous variable). Event count. Synchronous output event. Pulse width measurement. Input capture

Time base timer: One-minute count setting

Watchdog timer × 1

■ Serial interface

Synchronous type/UART (full-duplex) × 2: Serial 0, 1

Synchronous type/Single-master I^2C × 1: Serial 3

I^2C slave × 1: Serial 4

Serial 4.....I^2C high-speed transfer mode. 7-bit/10-bit address setting. General call

■ DMA controller

Maximum transfer cycles: 255

Starting factor: External request. Various types of interrupt. Software

Transfer mode: 1-byte transfer. Word transfer. Burst transfer

■ I/O Pins

I/O 53 : Common use. Specified pull-up resistor available. Input/output selectable (bit unit)

■ A/D converter

10-bit × 7 channels (with S/H)

■ D/A converter

8-bit × 2 channels (Serves as AD pin, as well)

■ Special Ports

Buzzer output. Remote control carrier output. High-current drive port

■ ROM Correction

Correcting address designation: Up to 3 addresses possible

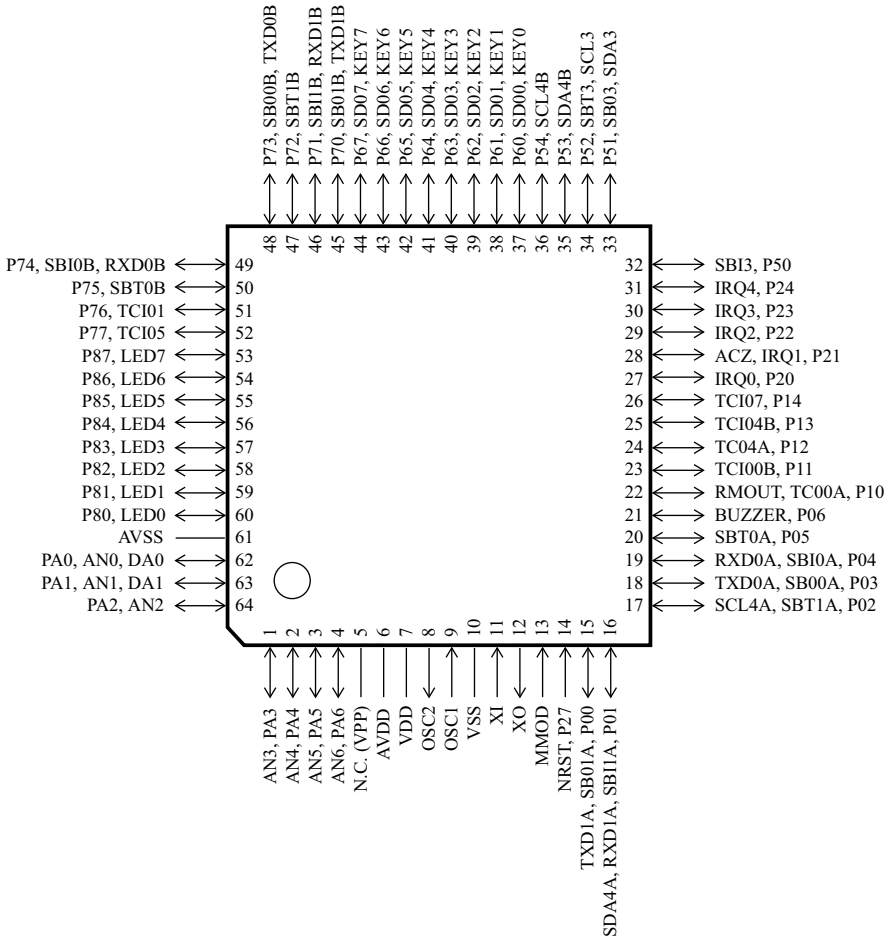
■ Electrical Charactreistics (Supply current)

Parameter	Symbol	Condition	Limit			Unit
			min	typ	max	
Operating supply current	IDD1	fosc = 20 MHz (fs = fosc/2). VDD = 3.3 V		6	12	mA
	IDD2	fosc = 8.39 MHz (fs = fosc/2). VDD = 3.3 V		3	6	mA
	IDD3	fx = 32.768 kHz (fs = fx/2). VDD = 3.3 V			40	µA
Supply current at HALT	IDD4	fx = 32.768 kHz. VDD = 3.3 V. Ta = 25 °C		5	10	µA
	IDD5	fx = 32.768 kHz. VDD = 3.3 V			40	µA
Supply current at STOP	IDD6	VDD = 3.3 V. Ta = 25 °C			2	µA
	IDD7	VDD = 3.3 V. Ta = 85 °C			30	µA

Ta = -40 °C to +85 °C. VDD = 1.8 V to 3.6 V. VSS = 0 V

■ Pin Assignment

LQFP064-P-1414, TQFP064-P-1010C [MN101C77C]



Note) Pin 5 serves as the VPP pin in the MN101CF77G, and cannot be used as a user pin.

Request for your special attention and precautions in using the technical information and semiconductors described in this book

(1) If any of the products or technical information described in this book is to be exported or provided to non-residents, the laws and regulations of the exporting country, especially, those with regard to security export control, must be observed.

(2) The technical information described in this book is intended only to show the main characteristics and application circuit examples of the products. No license is granted in and to any intellectual property right or other right owned by Panasonic Corporation or any other company. Therefore, no responsibility is assumed by our company as to the infringement upon any such right owned by any other company which may arise as a result of the use of technical information described in this book.

(3) The products described in this book are intended to be used for standard applications or general electronic equipment (such as office equipment, communications equipment, measuring instruments and household appliances).
Consult our sales staff in advance for information on the following applications:
- Special applications (such as for airplanes, aerospace, automobiles, traffic control equipment, combustion equipment, life support systems and safety devices) in which exceptional quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or harm the human body.
- Any applications other than the standard applications intended.

(4) The products and product specifications described in this book are subject to change without notice for modification and/or improvement. At the final stage of your design, purchasing, or use of the products, therefore, ask for the most up-to-date Product Standards in advance to make sure that the latest specifications satisfy your requirements.

(5) When designing your equipment, comply with the range of absolute maximum rating and the guaranteed operating conditions (operating power supply voltage and operating environment etc.). Especially, please be careful not to exceed the range of absolute maximum rating on the transient state, such as power-on, power-off and mode-switching. Otherwise, we will not be liable for any defect which may arise later in your equipment.
Even when the products are used within the guaranteed values, take into the consideration of incidence of break down and failure mode, possible to occur to semiconductor products. Measures on the systems such as redundant design, arresting the spread of fire or preventing glitch are recommended in order to prevent physical injury, fire, social damages, for example, by using the products.

(6) Comply with the instructions for use in order to prevent breakdown and characteristics change due to external factors (ESD, EOS, thermal stress and mechanical stress) at the time of handling, mounting or at customer's process. When using products for which damp-proof packing is required, satisfy the conditions, such as shelf life and the elapsed time since first opening the packages.

20080805